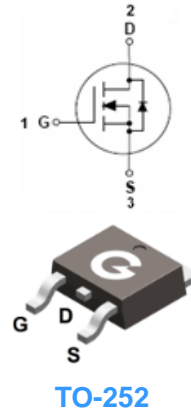


### Features

- Low power loss by high speed switching and low on-resistance
- Excellent thermal behavior
- Product validation acc. JEDEC Standard
- RoHS compliant with Halogen-free

HF



### Mechanical Data

- Case: TO-252
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solderability-per MIL-STD-202, Method 208

### Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
SJM65R380XD	TO-252	80 pcs / Tube & 2500 pcs / Tape & Reel	SJM65R380XD

### Maximum Ratings (@ $T_C = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-to-Source Voltage	$V_{DSS}$	650	V
Gate-to-Source Voltage	$V_{GSS}$	$\pm 30$	V
Continuous Drain Current ( $T_C = 25^\circ\text{C}$ )	$I_D$	11	A
Continuous Drain Current ( $T_C = 100^\circ\text{C}$ )		7	A
Pulsed Drain Current ( $t_p = 10\mu\text{s}$ , $T_C = 25^\circ\text{C}$ )	$I_{DM}$	44	A
Single Pulse Avalanche Energy <sup>*3</sup>	$E_{AS}$	200	mJ
Power Dissipation ( $T_C = 25^\circ\text{C}$ )	$P_D$	90	W
Operating Junction Temperature Range	$T_J$	-55 ~ +150	$^\circ\text{C}$
Storage Temperature Range	$T_{STG}$	-55 ~ +150	$^\circ\text{C}$

### Thermal Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	-	-	1.4	$^\circ\text{C/W}$
Thermal Resistance Junction-to-Air <sup>*1</sup>	$R_{\theta JA}$	-	-	62	$^\circ\text{C/W}$

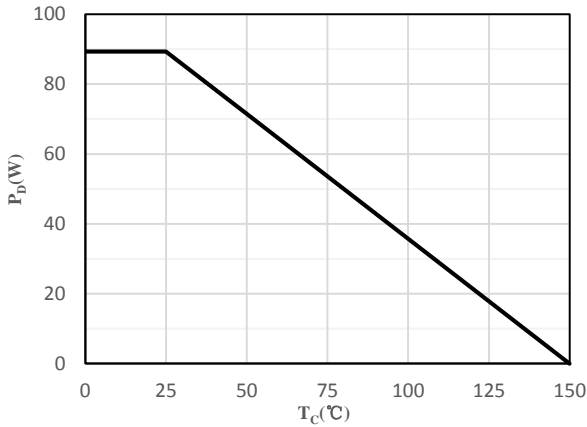
### Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
<b>Static Characteristics</b>						
$V_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	650	-	-	V
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 650V, V_{GS} = 0V$	-	-	1	$\mu A$
$I_{GSS}$	Gate-Body Leakage Current	$V_{GS} = \pm 30V, V_{DS} = 0V$	-	-	$\pm 100$	nA
<b>On Characteristics</b>						
$R_{DS(ON)}$	Drain-Source On-resistance *2	$V_{GS} = 10V, I_D = 4A$	-	0.33	0.38	$\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	2.5	3.7	4.5	V
$R_G$	Gate Resistance	$V_{GS} = 0V, f = 1MHz$	-	4.1	-	$\Omega$
<b>Dynamic Characteristics</b>						
$C_{ISS}$	Input Capacitance	$V_{GS} = 0V$ $V_{DS} = 40V$ $f = 250kHz$	-	678	-	pF
$C_{OSS}$	Output Capacitance		-	158	-	
$C_{RSS}$	Reverse Transfer Capacitance		-	2.5	-	
<b>Switching Characteristics</b>						
$t_{d(ON)}$	Turn-on Delay Time	$V_{DD} = 480V$ $V_{GS} = 15V$ $I_D = 4A$ $R_G = 3.3\Omega$	-	26	-	ns
$t_r$	Turn-on Rise Time		-	32	-	
$t_{d(OFF)}$	Turn-Off Delay Time		-	41	-	
$t_f$	Turn-Off Fall Time		-	65	-	
$Q_G$	Total Gate-Charge	$V_{DD} = 480V$ $V_{GS} = 10V$ $I_D = 4A$	-	19.6	-	nC
$Q_{GS}$	Gate to Source Charge		-	4	-	
$Q_{GD}$	Gate to Drain (Miller) Charge		-	10.7	-	
<b>Source-Drain Diode Characteristics</b>						
$V_{SD}$	Diode Forward Voltage *2	$I_{SD} = 4A, V_{GS} = 0V$	-	0.81	1.2	V
$t_{rr}$	Reverse Recovery Time	$I_F = 4A, V_R = 100V$ $di/dt = 100A/\mu s$	-	230	-	ns
$Q_{rr}$	Reverse Recovery Charge		-	2	-	$\mu C$

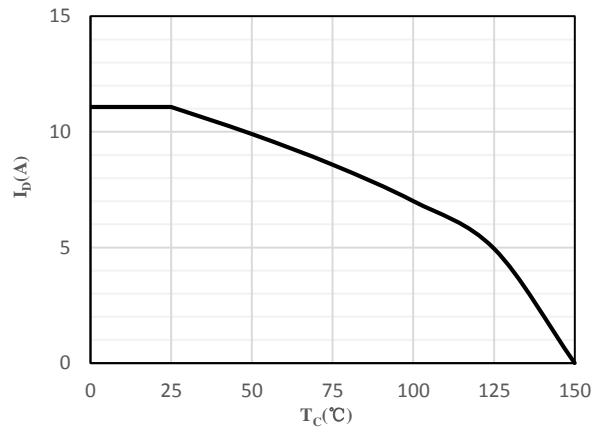
Notes:

- The data tested by surface mounted on a minimum recommended FR-4 board
- The data tested by pulsed, pulse width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$
- The  $E_{AS}$  data shows Max. rating. The test condition is  $V_{DD} = 100V, V_{GS} = 15V, L = 50mH$

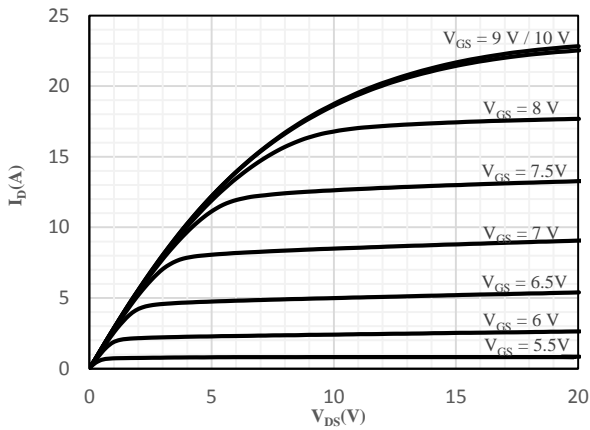
**Ratings and Characteristics Curves** (@  $T_A = 25^\circ\text{C}$  unless otherwise specified)



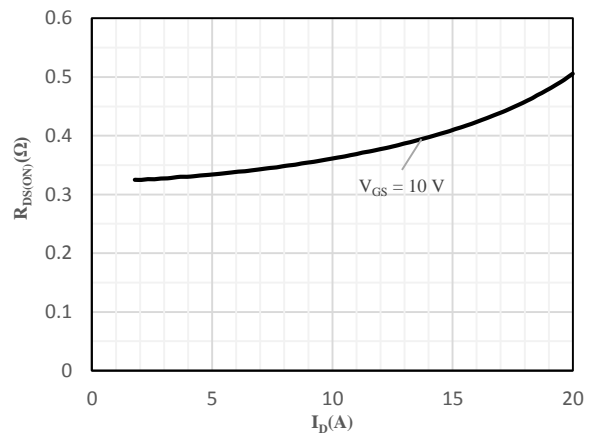
**Fig 1 Power Dissipation**



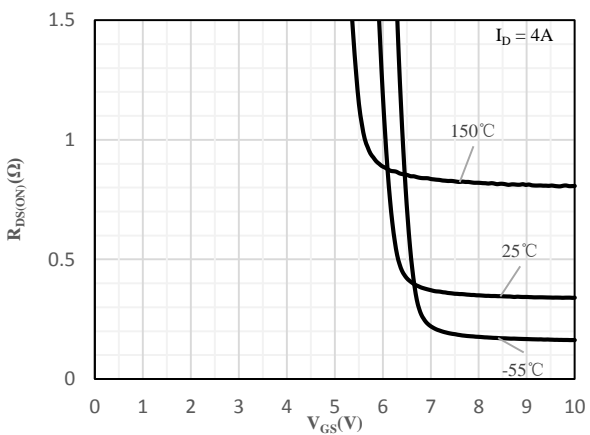
**Fig 2 Drain Current**



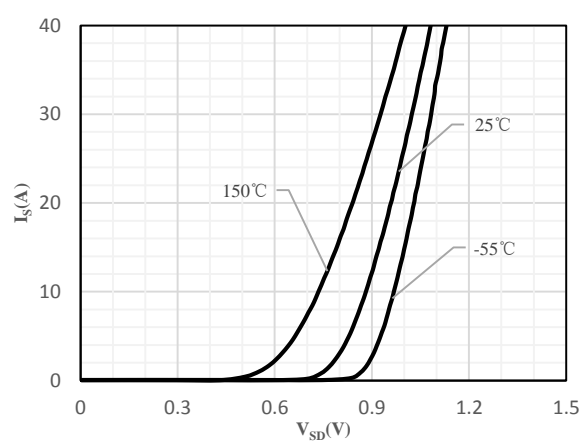
**Fig 3 Typical Output Characteristics**



**Fig 4 On-Resistance vs. Drain Current and Gate Voltage**



**Fig 5 On-Resistance vs. Gate-Source Voltage**



**Fig 6 Body-Diode Characteristics**

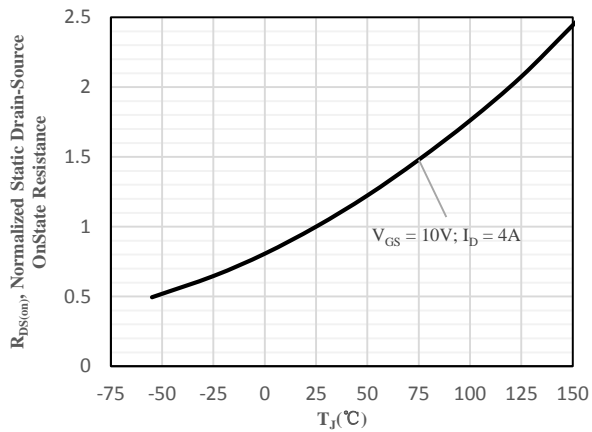


Fig 7 Normalized On-Resistance vs. Junction Temperature

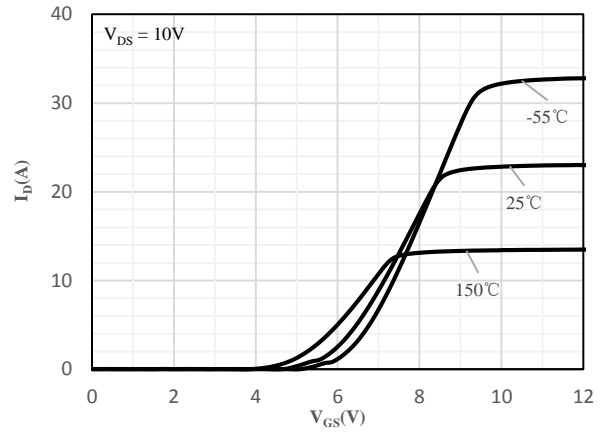


Fig 8 Transfer Characteristics

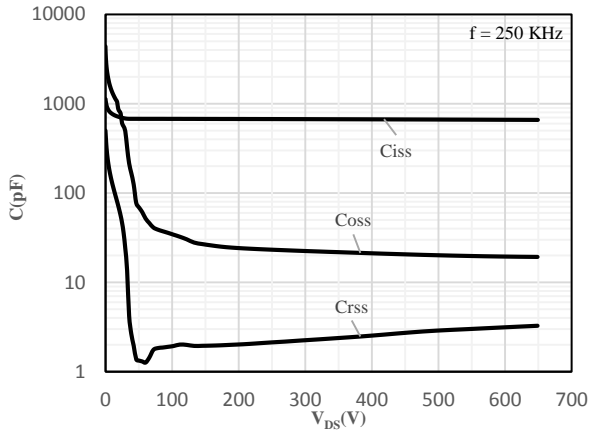


Fig 9 Capacitance Characteristics

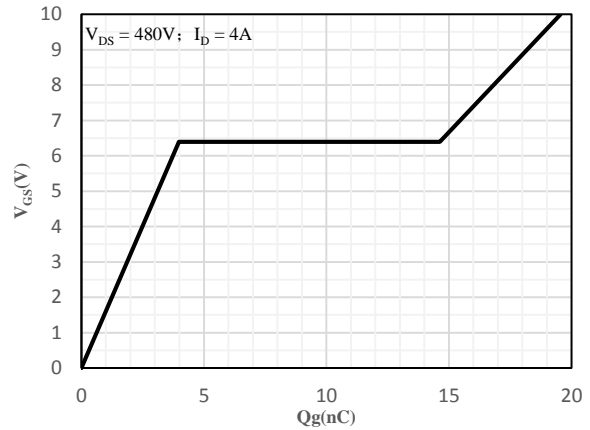


Fig 10 Gate-Charge Characteristics

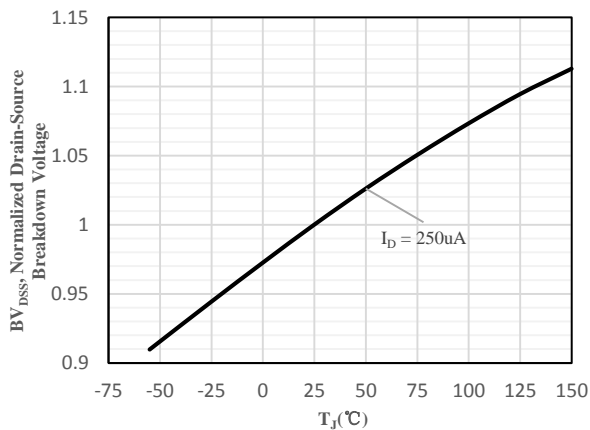


Fig 11 Normalized Breakdown Voltage vs. Junction Temperature

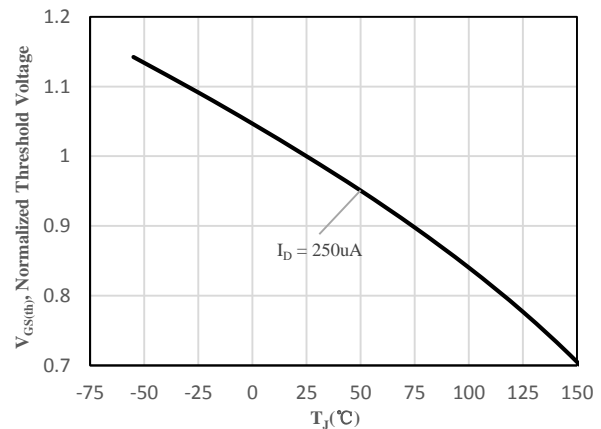
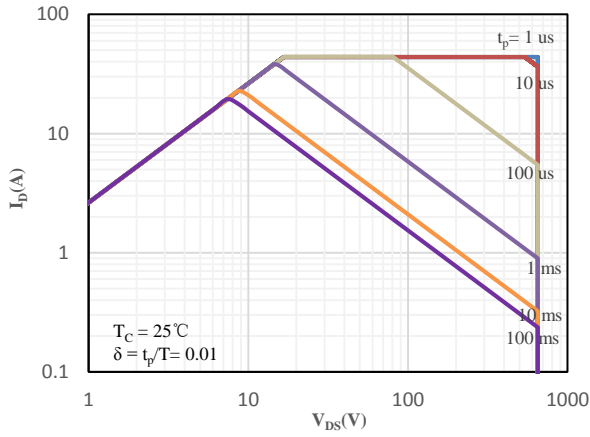
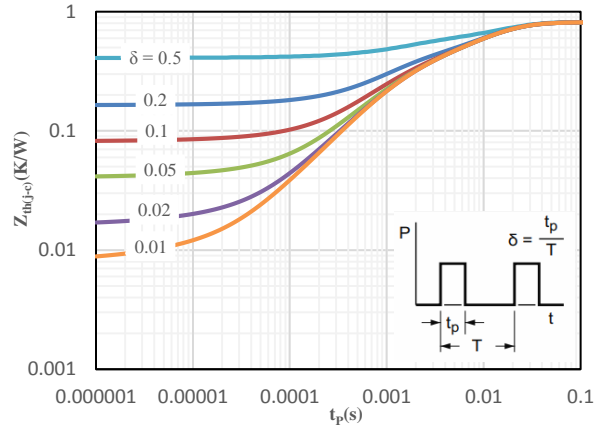


Fig 12 Normalized  $V_{GS(th)}$  vs. Junction Temperature

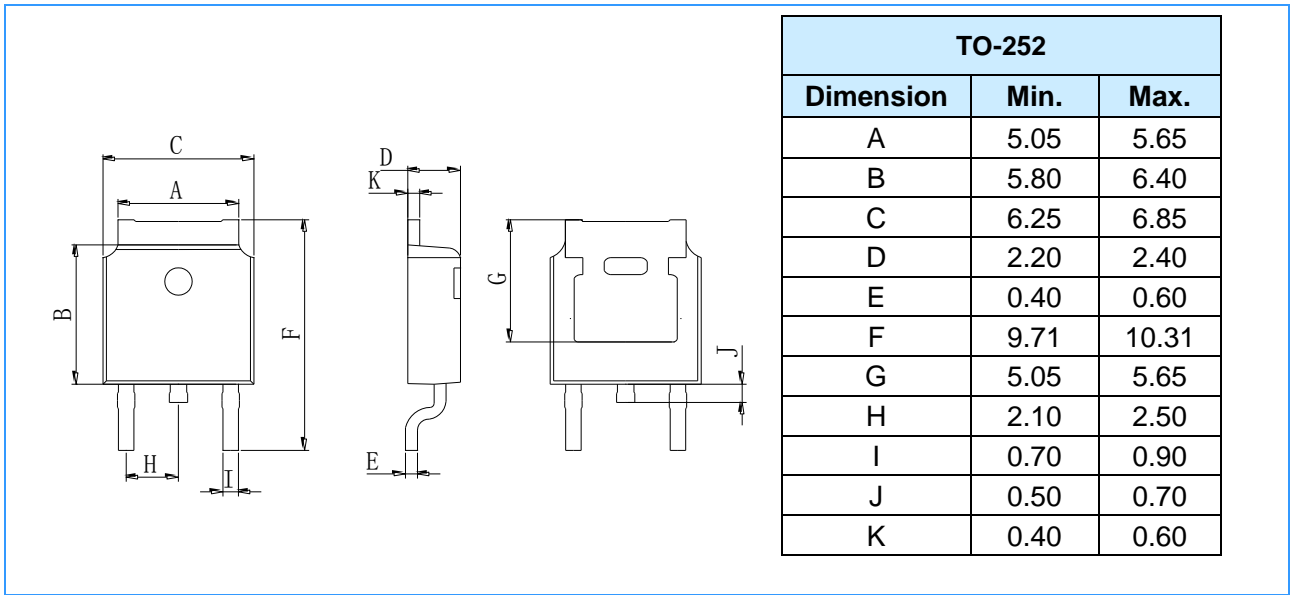


**Fig 13 Safe Operation Area**



**Fig 14 Maximum transient thermal impedance**

Package Outline Dimensions (Unit: mm)



Mounting Pad Layout (Unit: mm)

